

1 Dibenzoquinethiophene- and Dibenzosexithiophene-Based Hole- 2 Transporting Materials for Perovskite Solar Cells

3 Javier Urieta-Mora,^{†,‡} Iwan Zimmermann,[‡] Juan Aragón,[§] Agustín Molina-Ontoria,^{*,||}
4 Enrique Ortí,^{*,§} Nazario Martín,^{*,†,||} and Mohammad Khaja Nazeeruddin^{*,‡,||}

5 [†]Departamento Química Orgánica, Facultad C. C. Químicas, Universidad Complutense de Madrid, Av. Complutense s/n, 28040
6 Madrid, Spain

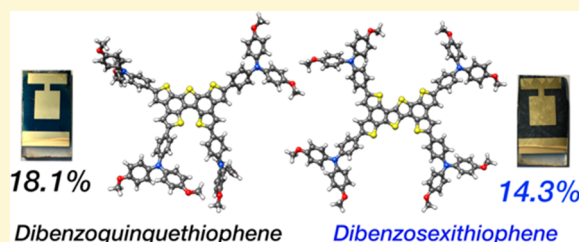
7 [‡]Group for Molecular Engineering of Functional Materials, EPFL VALAIS, CH-1951 Sion, Switzerland

8 [§]Instituto de Ciencia Molecular, Universidad de Valencia, Catedrático José Beltrán 2, 46980 Paterna, Spain

9 ^{||}IMDEA-Nanociencia, C/Faraday 9, Ciudad Universitaria de Cantoblanco, 28049 Madrid, Spain

10 **S** Supporting Information

11 **ABSTRACT:** Fused oligothiophene-based π -conjugated organic
12 derivatives have been widely used in electronic devices. In particular,
13 two-dimensional (2D) heteroarenes offer the possibility of broad-
14 ening the scope by extending the π -conjugated framework, which
15 endows enhanced charge transport properties due to the potential
16 intermolecular π - π stacking. Here, the synthesis and characterization
17 of two new small-molecule hole-transporting materials (HTMs) for
18 perovskite solar cells (PSCs) are reported. The newly custom-made
19 compounds are based on dibenzoquinethiophene (DBQT) and
20 dibenzosexithiophene (DBST) cores, which are covalently linked to triphenylamine moieties to successfully afford the four-
21 armed tetrakis(triphenylamine) (TTPA) derivatives TTPA-DBQT and TTPA-DBST. The combination of these novel central
22 scaffolds with the electron-donor TTPA units bestow the resulting HTMs with the appropriate energy levels and, therefore,
23 good electronic contact with the perovskite for extracting the hole efficiently. TTPA-DBQT surpasses TTPA-DBST not only
24 in terms of conductivity but also in light-to-energy conversion efficiency using conventional mesoscopic n-i-p perovskite
25 devices, 18.1% and 14.3%, respectively. These results were systematically compared with the benchmark HTM, 2,2',7,7'-
26 tetrakis(*N,N*-di-*p*-methoxyphenylamine)-9,9'-spirobifluorene (spiro-OMeTAD). Additionally, scanning electron microscopy
27 (SEM) hints that TTPA-DBQT forms high quality and fully homogeneous films, whereas TTPA-DBST leads to the
28 formation of thinner films with pinholes, which explains its lower fill factor despite its better hole-extraction properties owing to
29 its more planar π -extended scaffold.



30 ■ INTRODUCTION

31 Pressed by the drastic reduction of fossil fuels, harvesting
32 energy by alternative sources has become one of the most
33 important challenges that our society will face in the coming
34 years. In this regard, the immense amount of energy that we
35 receive from our sun can be considered as the main source of
36 power for our future society. Nowadays, solar cell devices
37 based on silicon are leading the photovoltaic sector, trans-
38 forming 25% of the incident sunlight into electricity.
39 Notwithstanding, these high-power conversion efficiency
40 (PCE) values for silicon solar cells, the high production cost
41 of these cells has encouraged the quest for new low-cost and
42 efficient photovoltaic devices.

43 Since the advent of the hybrid inorganic-organic perovskite
44 solar cells (PSCs) reported by Miyasaka and co-workers as
45 sensitizers for dye-sensitized solar cells (DSSCs),¹ PSCs have
46 emerged as a promising technology for light harvesting in the
47 future, displaying efficiencies over 22.7%.² Hybrid perovskites
48 usually contain small organic cations, such as methylammo-
49 nium (MA) or formamidinium (FA), and lead halides (e.g.,

MAPbI₃) and exhibit extraordinary properties such as high
50 charge-carrier mobilities,³⁻⁵ tunable band gap energy,⁶ long
51 free charge-carrier diffusion lengths,⁷⁻⁹ wide light absorption,¹⁰
52 and solution-processed fabrication. Perovskites allow the
53 preparation of different device architectures depending on
54 the charge selective contacts used to sandwich the perovskite.
55 To date, the most featured and efficient devices are based on
56 mesoporous structures, where the perovskite is infiltrated in a
57 dense mesoporous scaffold of TiO₂ (mp-TiO₂), in combina-
58 tion with organic hole-transporting materials (HTMs), the
59 most widely used HTM being the 2,2',7,7'-tetrakis(*N,N*-di-*p*-
60 methoxyphenylamine)-9,9'-spirobifluorene (spiro-OMeTAD)
61 compound.^{11,12}

62 Despite its great performance, spiro-OMeTAD presents a
63 relatively high commercial price owing to its tough (Grignard
64

Special Issue: Jean-Luc Bredas Festschrift

Received: September 20, 2018

Revised: December 5, 2018

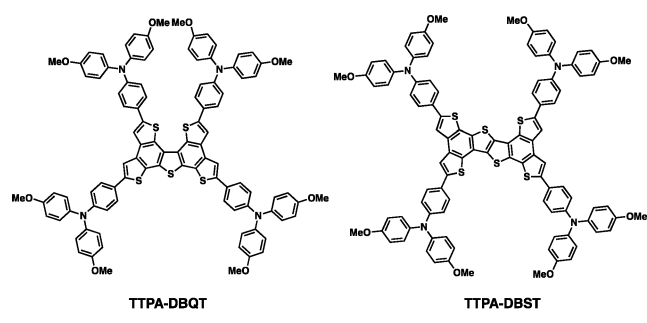
Published: December 7, 2018

65 reaction, bromination reaction, and a Hartwig–Buchwald C–
66 N coupling) and low-yield (less than 40%) synthetic
67 preparation and costly purification.¹³ These drawbacks have
68 promoted the design and synthesis of alternative new HTMs.
69 In this regard, different types of organic HTMs, with and
70 without the spiro-motif,^{14–17} from classical polymers or
71 oligomers to small π -conjugated structures, have been
72 investigated in PSCs.^{18–20}

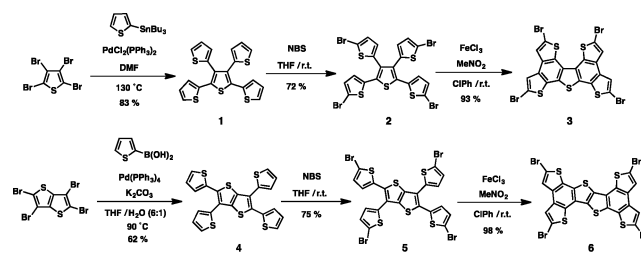
73 Flat, sulfur-containing, polycyclic aromatic structures have
74 been extensively used in the literature for field-effect transistors
75 OFETs²¹ and photovoltaic applications^{22–24} because they give
76 rise to planar structures and the sulfur-rich arenes introduce
77 extra intermolecular interactions (π – π , S \cdots S) that affect the
78 packing of the derivatives (face-to-edge to face-to-face), thus
79 enhancing the hole-carrier mobilities. These chalcogenide-rich
80 polycyclic aromatics have been recently described as promising
81 scaffolds for building novel HTMs for PSCs due to their good
82 conductivity and excellent performance.^{25–27} This behavior is
83 beautifully exemplified by anthra[1,2-*b*:4,3-*b'*:5,6-*b''*:8,7-*b'''*]-
84 tetrathiophene (ATT) derivatives introduced by Zimmermann
85 et al. as HTMs, where π – π stacking is surmised as one of the
86 main reasons for their enhanced conductivity and efficiency in
87 PSCs.²⁸

88 Inspired by these findings, we present herein two new
89 HTMs, in which the π -conjugation of the central core has been
90 systematically modulated. Particularly important in this design
91 is to control the molecular packing by introducing highly
92 planar structures, which is an important parameter for
93 enhancing carrier mobilities. Promoting the intermolecular
94 assembly by π – π and S \cdots S interactions serves as a powerful
95 paradigm for the design of more efficient HTMs. On this basis,
96 we have synthesized two novel sulfur-rich cores, dibenzoquin-
97 quethiophene (DBQT) and dibenzosexithiophene (DBST), to
98 which four triphenylamine (TPA) units are attached at the α -
99 position of the four terminal thiophene rings giving rise to the
100 tetrakis(triphenylamine) (TTPA) derivatives sketched in Chart
101 1. The new derivatives TTPA–DBQT and TTPA–DBST not

Chart 1. Chemical Structures of the Two New HTMs



Scheme 1. Synthetic Procedure for the Preparation of DBQT (3) and DBST (6) Cores



Supporting Information for experimental details). The
DBQT and DBST cores were prepared by a 4-fold Pd-
mediated Stille cross-coupling reaction or Pd-mediated Suzuki
coupling reaction between commercially available tetrabromo
derivatives and 2-(tributyl)stannylthiophene or 2-thienylbor-
onic acid affording compounds 1 and 4, respectively, which
were then converted into the tetrabromo derivatives 2 and 5 by
a regioselective bromination reaction in α -position. Utilizing a
FeCl₃-mediated oxidative C–C coupling protocol, π -extended
derivatives 3 and 6 were cleanly obtained in excellent yields.
Finally, a 4-fold Suzuki cross coupling reaction with *p*-
methoxytriphenylamine successfully furnished TTPA–DBQT
and TTPA–DBST as orange solids, in 74% and 68% yields,
respectively.

Complete structural characterization of the designed
TTPA–DBQT and TTPA–DBST HTMs and the corre-
sponding intermediates was conducted by using standard
spectroscopic techniques such as ¹H NMR, ¹³C NMR, FTIR,
and UV–visible (for more details, see the Supporting
Information). Mass spectrometry (MALDI-TOF) confirmed
the presence of TTPA–DBQT and TTPA–DBST with
molecular ion peaks [M]⁺ at 1620.4273 and 1676.3986 *m/z*,
respectively.

Theoretical Calculations. To gain insight into the
structural and electronic properties of the TTPA–DBQT
and TTPA–DBST compounds, density functional theory
(DFT) calculations were performed at the B3LYP/6-31G**
level in the presence of the solvent (CH₂Cl₂). Their respective
cores (DBQT and DBST), the pendant triphenylamine TPA
moiety, and the reference spiro-OMeTAD compound were
also computed for comparison purposes (see the Supporting
Information for full computational details).

Figure S1 displays the most representative bond length
values calculated at the B3LYP/6-31G** level for the DBQT
and DBST cores and the TTPA–DBQT and TTPA–DBST
HTMs. The DBQT and DBST cores can be visualized as
formed by two benzotrithiophene (BTT) units. In the case of
DBQT, the two BTT units share the central thiophene ring
and define a conjugated all-*syn* 2,2',5',2''-terthiophene with the
external thiophene rings. Due to the condensation with the
adjacent benzenes, the central thiophene ring exhibits longer
carbon–carbon (C–C) bonds (1.417–1.479 Å) than the
external thiophene rings (1.372–1.432 Å), the latter being
more similar to those found for nonfused thiophene
oligomers.²⁹ In the case of the DBST core, the two BTT
units define a central fused bithienyl unit with C–C bond
lengths more similar to those expected for fused oligothio-
phenes,³⁰ which is conjugated with two external thiophene
rings in a *syn* 2,2'-disposition. Therefore, both the DBQT and
the DBST core present an effective conjugation path between
the thiophene rings connected by the 2,2'-positions. For the

only exhibit a proper energy alignment of the highest-occupied
molecular orbital (HOMO), which ensures efficient hole
injection to the perovskite, but also good conductivity values.
Power conversion efficiencies of up to 18.1% are derived from
mesoscopic perovskite solar cells using the new HTMs and the
compositionally engineered perovskite [FAP-
bI₃]_{0.85}[MAPbBr₃]_{0.15}, which is comparable to the PCE value
obtained for the state-of-the-art spiro-OMeTAD.

RESULTS AND DISCUSSION

Synthesis. The new HTMs were built up following similar
synthetic pathways as described in Scheme 1 (see the

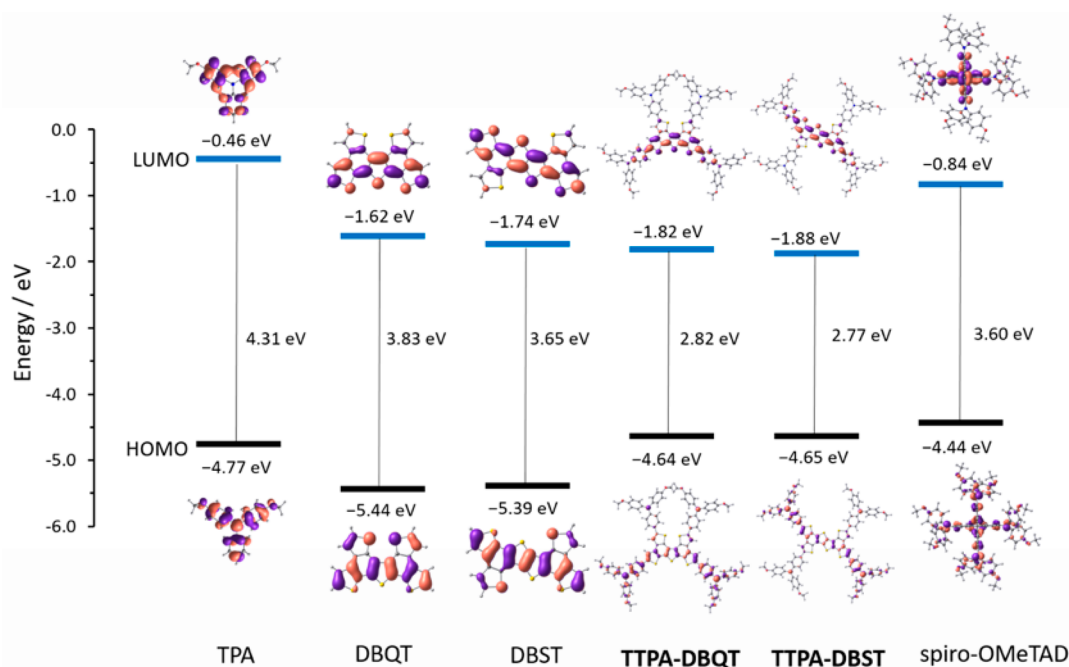


Figure 1. Energy diagram displaying the frontier molecular orbitals computed at the B3LYP/6-31G** level for the TPA unit, the DBQT and DBST cores, the TTPA-DBQT and TTPA-DBST HTMs, and the spiro-OMeTAD reference compound.

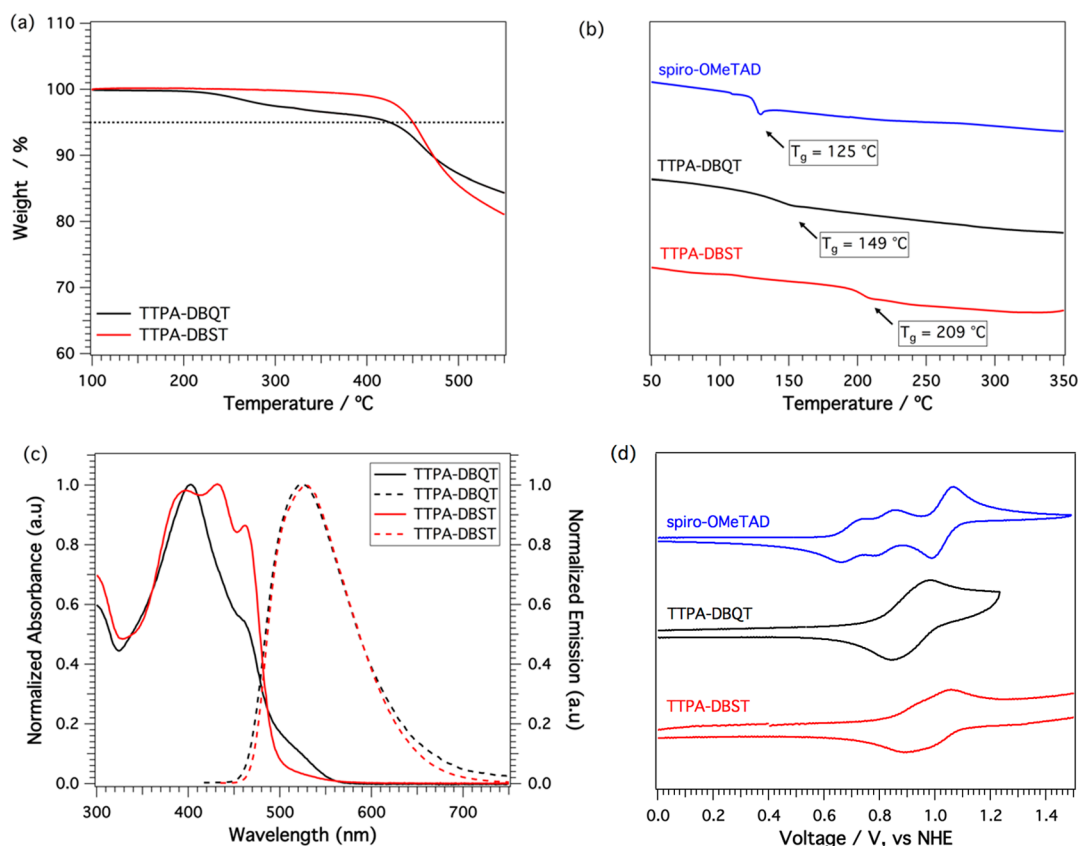


Figure 2. (a) Thermogravimetric analysis curves recorded for TTPA-DBQT and TTPA-DBST under nitrogen at $10\text{ }^{\circ}\text{C min}^{-1}$ of heating rate. (b) Differential scanning calorimetry of spiro-OMeTAD, TTPA-DBQT, and TTPA-DBST under nitrogen at a heating rate of $20\text{ }^{\circ}\text{C min}^{-1}$ (second cycle). (c) UV-vis absorption (solid line) and fluorescence emission spectra (dashed line) of TTPA-DBQT and TTPA-DBST derivatives in CH_2Cl_2 , measured at ambient temperature. (d) Cyclic voltammograms of TTPA-DBQT and TTPA-DBST derivatives in TBAPF₆/ CH_2Cl_2 at a scan rate of 100 mV s^{-1} .

164 HTMs, the insertion of the four TPA units hardly causes any
165 substantial change in the bond distances of the conjugated

core, with the exception of the terminal C-C and carbon-sulfur bonds to which the TPA units are linked (Figure S1). It 167

Table 1. Thermal, Electrochemical, and Photophysical Properties of TTPA–DBQT, TTPA–DBST, and spiro-OMeTAD

HTM	$T_{\text{dec}} [^{\circ}\text{C}]^a$	$T_g [^{\circ}\text{C}]^b$	$E_{1/2}^{\text{ox}} [\text{V}]^c$	$E_{\text{HOMO}} [\text{eV}]^d$	$\lambda_{\text{max,abs}} [\text{nm}]^e$	$\lambda_{\text{max,em}} [\text{nm}]^e$	$E^{0-0} [\text{eV}]^f$	$E_{\text{LUMO}} [\text{eV}]^g$
TTPA–DBQT	423	149	0.88	–5.32	403	522	2.60	–2.72
TTPA–DBST	450	209	0.93	–5.37	431	528	2.57	–2.80
spiro-OMeTAD	449	125	0.72	–5.16	386	319	3.05	–2.11

^aDecomposition temperature determined from TGA (5% weight loss under a N₂ atmosphere). ^bDetermined from the second cycle of the DSC under a N₂ atmosphere. ^cDetermined from CV measurements vs normal hydrogen electrode (NHE). ^d E_{HOMO} is estimated in eV by $E_{\text{HOMO}} = -4.44 \text{ eV} - E_{1/2}^{\text{ox}}$. ^e λ_{max} of absorption and emission was measured in CH₂Cl₂ solutions. ^f E^{0-0} was determined at the intersection of normalized absorption and emission spectra. ^g E_{LUMO} was estimated by $E_{\text{LUMO}} = E_{\text{HOMO}} + E^{0-0}$.

168 should be emphasized that both HTMs preserve the planarity
169 of the polycyclic core (Figure S2).

170 Figure 1 displays the frontier molecular orbitals calculated
171 for TPA, the DBQT and DBST cores, the TTPA–DBQT and
172 TTPA–DBST HTMs, and the spiro-OMeTAD reference
173 compound. The highest-occupied molecular orbital (HOMO)
174 of the DBQT and DBST cores, computed at –5.44 and –5.39
175 eV, respectively, are significantly lower in energy than the
176 HOMO of TPA (–4.77 eV) in accord with their weaker
177 electron-donor character. In line with the molecular structure,
178 the HOMOs of DBQT and DBST mainly spread over the
179 most effective conjugated path and their topology resembles
180 those obtained for oligothiophene derivatives.^{31,32} The
181 HOMOs of the four-armed DBQT and DBST derivatives are
182 significantly destabilized (–4.64 and –4.65 eV, respectively) as
183 a consequence of the incorporation of the TPA moieties. This
184 destabilization, which implies an enhancement of the electron-
185 donor character, shifts up the HOMO levels close to that
186 computed for the reference spiro-OMeTAD (–4.44 eV). Note
187 that the HOMO of both TTPA–DBQT and TTPA–DBST
188 spreads not only over the respective cores but also over the
189 TPA moieties connected to the thiophene rings where the
190 conjugation is more effective. It should be noted that a
191 significant charge transfer occurs from the peripheral TPA
192 groups to the sulfur-rich central cores, which hold a total net
193 charge of –0.55e and –0.56e for TTPA–DBQT and TTPA–
194 DBST, respectively. The obtained electronic structure of the
195 TTPA–DBQT and TTPA–DBST HTMs is therefore
196 significantly polarized.

197 **Thermal and Optical Properties.** Thermogravimetric
198 analysis (TGA) of the new HTMs revealed their good thermal
199 stability (5% weight loss under N₂ atmosphere) up to 450 °C
200 for TTPA–DBST and 423 °C for TTPA–DBQT, which
201 demonstrates the robustness of these HTMs (Figure 2a). The
202 latter exhibits a slight weight loss (3%) in the range of 150–
203 350 °C, which is attributed to traces of solvent molecules
204 trapped after purification of the material. Detailed thermal
205 features are collected in Table 1. The thermal behavior of
206 TTPA–DBQT and TTPA–DSQT was inspected by means of
207 differential scanning calorimetry (DSC) (Figure 2b). Glass
208 transition temperatures (T_g) were determined from the second
209 heating cycle. Both molecules exhibit reduced tendency to
210 crystallize with a glass transition temperature of 149 °C for
211 TTPA–DBQT and 209 °C for TTPA–DBST, which confirms
212 their amorphous behavior. T_g is indeed higher for the two new
213 HTM derivatives in comparison with that for spiro-OMeTAD
214 ($T_g = 125$ °C), which is attributed to improved molecular
215 packing, indicating higher stability in the amorphous state.

216 The absorption and emission spectra of the new HTMs are
217 shown in Figure 2c, and the corresponding data are collected
218 in Table 1. In CH₂Cl₂, TTPA–DBQT and TTPA–DBST
219 display an intense absorption in the UV and at short

wavelengths of the visible region (<500 nm), in sharp contrast
220 with the limited absorbance of spiro-OMeTAD in the visible.
221 The absorption maxima ($\lambda_{\text{max,abs}}$) for TTPA–DBQT and
222 TTPA–DBST are centered at 403 nm ($\epsilon = 1.2 \times 10^4 \text{ M cm}^{-1}$)
223 and 431 nm ($\epsilon = 1.4 \times 10^4 \text{ M cm}^{-1}$), respectively. The broader
224 and red-shifted absorption of TTPA–DBST compared with
225 TTPA–DBQT is ascribed to the more extended π -conjugation
226 of the central DBST fragment and is in agreement with the
227 lower HOMO–LUMO gap predicted for TTPA–DBST
228 (Figure 1). B3LYP/6-31G** calculations of the lowest-lying
229 singlet excited electronic states ascribe the broad experimental
230 absorption band recorded for TTPA–DBQT to six intense S_0
231 $\rightarrow S_n$ ($n = 1-6$) electronic transitions computed in the 429–
232 505 nm range. For TTPA–DBST, three intense electronic
233 transitions ($S_0 \rightarrow S_1$, $S_0 \rightarrow S_2$, and $S_0 \rightarrow S_6$) computed in the
234 420–513 nm range seem to be responsible for the more
235 structured experimental band. The intense electronic tran-
236 sitions in both HTMs are of $\pi-\pi^*$ nature and imply one-
237 electron promotions from the HOMO – 3, HOMO – 2,
238 HOMO – 1, and HOMO to the LUMO, LUMO + 1, and
239 LUMO + 2, which reside on both the core and the peripheral
240 TPA groups (see Table S1 and Figure S3). The emission
241 maximum of TTPA–DBQT is located at 522 nm, whereas that
242 of TTPA–DBST displays a slight bathochromic shift peaking
243 at 528 nm. Furthermore, it is observed that the intersection of
244 the absorption and emission occurs at 477 and 481 nm for
245 TTPA–DBQT and TTPA–DBST, respectively, which corre-
246 sponds to analogous band gap energy values of 2.60 and 2.57
247 eV, respectively.
248

Electrochemical Properties. The redox properties of the
249 novel HTM were investigated by cyclic voltammetry (CV) in
250 TBAPF₆/CH₂Cl₂ at a scan rate of 100 mV s^{–1} (Figure 2d). For
251 better understanding, spiro-OMeTAD was also measured
252 under the same experimental conditions. The oxidation
253 potentials and the HOMO energies are summarized in Table
254 1. The cyclic voltammogram of TTPA–DBQT shows one
255 oxidation wave with $E_{1/2}$ values of 0.88 V vs NHE. The broad
256 shape of the oxidation wave seems to result from the
257 overlapping of two oxidation waves that can be tentatively
258 assigned to consecutive very close oxidation processes where
259 four electrons are successively extracted from the TPA units.
260 However, the TTPA–DBST exhibits two waves at 0.93 and
261 1.02 V vs NHE, respectively. The different central moieties do
262 not have a strong impact on the electrochemical properties.
263 The HOMO energies derived from the first oxidation potential
264 for TTPA–DBQT and TTPA–DBST are –5.32 and –5.37
265 eV, respectively, which are ~0.2 eV lower than the energy
266 obtained for spiro-OMeTAD (–5.16 eV) and in very good
267 accord with the theoretical values estimated for the isolated
268 molecules (Figure 1). Therefore, an efficient hole extraction
269 from the perovskites to the HTMs is ensured due to the 270

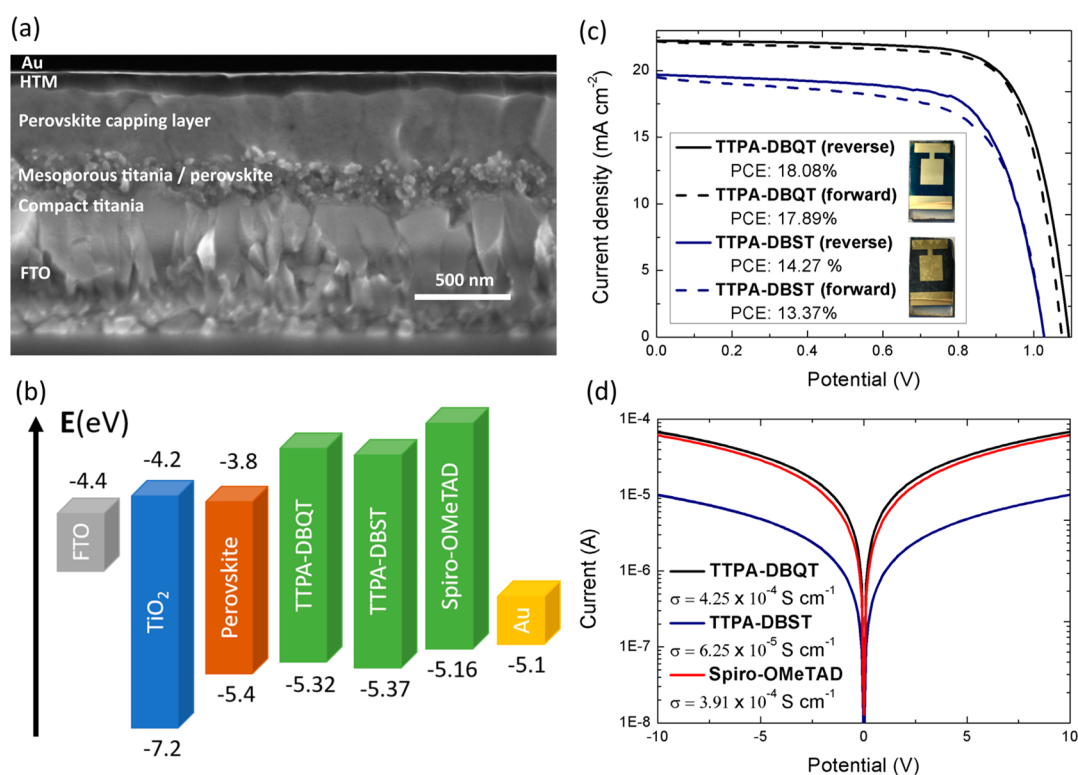


Figure 3. Device characterization: (a) SEM cross-section image of a PSC having TTPA-DBQT as HTM. (b) Energy diagram of the different components used in the PSC. (c) Solar cell efficiency of the champion devices measured under 1.5G simulated sunlight. (d) Conductivity of the different HTMs measured on substrates having interdigitating gold electrodes.

271 excellent band alignment with the valence band edge of the
272 perovskite (ca. -5.4 eV).

273 To gain a better understanding of the oxidation processes,
274 the oxidized species (up to the tetracation) of TTPA-DBQT
275 and TTPA-DBST were calculated at the B3LYP/6-31G**
276 level in CH_2Cl_2 . Table S1 gathers the charges accumulated by
277 the constituting fragments (central cores and TPA units) as
278 oxidation takes place. In line with the topology of the HOMO
279 of TTPA-DBQT and TTPA-DBST (Figure 1), the charge
280 for the radical cation species is mainly extracted from the
281 DBQT and DBST cores (ca. $0.30e$) and the TPA units linked
282 to the terminal 2-positions of the thiophene rings (ca. $0.27e$)
283 that define the most effective conjugation pathway within the
284 cores. Upon further oxidation, the charge is steadily drawn
285 from the four TPA units. For the tetracation, they hold a
286 similar charge of ca. $+1.0e$ and the cores lose the excess of
287 electron density shown in the neutral state (Table S1). It
288 should be noted that, for both TTPA-DBQT and TTPA-
289 DBST, the ionization energies (IEs) required for passing from
290 the neutral molecule to the cation (IE1), from the cation to the
291 dication (IE2), from the dication to the trication (IE3), and
292 from the trication to the tetracation (IE4) are predicted to
293 have relatively close values. For instance, the IE1, IE2, IE3, and
294 IE4 values for TTPA-DBQT were calculated to be 4.55, 4.79,
295 5.00, and 5.09 eV, respectively, and very similar values (4.57,
296 4.79, 4.95, and 5.05 eV, respectively) were obtained for
297 TTPA-DBST. The largest difference in IE values is between
298 IE1 and IE2 (0.24 and 0.22 eV for TTPA-DBQT and
299 TTPA-DBST, respectively). The closeness of the IE values
300 explains the electrochemical behavior found for TTPA-
301 DBQT and TTPA-DBST showing a broad four-electron
302 oxidation wave (Figure 2d).

Hole reorganization energies (λ) were calculated at the 303
B3LYP/6-31G** level in gas phase to evaluate the capability of 304
the TTPA-DBQT and TTPA-DBST compounds as HTMs 305
(see the planar core). Both TTPA-DBQT and TTPA-DBST 306
exhibit low reorganization energy similar to those found for 307
other excellent *p*-type semiconducting organic materials^{33,34} 308
and in the same range as that obtained for the reference spiro- 309
OMeTAD (0.139 eV).²⁸ Therefore, TTPA-DBQT and 310
TTPA-DBST present a great potential as hole-transporting 311
materials for PSC devices owing to its small λ value and the 312
appropriate energy level alignment with the valence band edge 313
of the perovskite. 314

Photovoltaics Properties. Solution-processed perovskite 315
solar cells were prepared to investigate the performance of the 316
novel HTMs compared to the widely used reference 317
compound spiro-OMeTAD. The photovoltaic devices were 318
fabricated following a standard procedure for the well-studied 319
n-i-p configuration with a mixed ion perovskite (FAP- 320
 bI_3)_{0.85}(MAPbBr₃)_{0.15} as the active light-harvesting material, 321
previously reported to yield high efficiencies.³⁵ The solar cells 322
consist of a stack of thin film layers deposited onto a FTO 323
substrate. Titania was used as the electron-selective contact 324
sandwiching the light-absorbing perovskite material with the 325
HTM. The perovskite layer was obtained using a one-step 326
spin-coating process using chlorobenzene as quenching solvent 327
as previously described by Jeon et al.³⁶ The HTMs were 328
applied on top of the perovskite film by spin-coating their 329
corresponding solutions in chlorobenzene for TTPA-DBQT 330
and spiro-OMeTAD and tetrachloroethane for TTPA-DBST, 331
respectively. Tetrachloroethane was used instead of chlor- 332
obenzene due to the low solubility of TTPA-DBST. Tert- 333
butylpyridine (*t*-BP), tris(2-(1*H*-pyrazol-1-yl)-4-*tert*- 334

butylpyridine)cobalt(III) (FK209), and tris(bis(trifluoromethylsulfonyl)imide) (Li-TFSI) were added as additives. Further details on the device fabrication can be found in the Supporting Information. The individual thin film layers of a PSC device can be observed from the cross-sectional scanning electron microscopy (SEM) image shown in Figure 3a where TTPA-DBQT was applied as the HTM. Energy levels of the different HTMs as well as other components in the PSC can be found in Figure 3b.

Device efficiencies were investigated under AM 1.5G (100 mW cm⁻²) simulated sunlight. The *J*-*V* curves of the champion devices using TTPA-DBQT and TTPA-DBST are shown in Figure 3c, and the corresponding reference using spiro-OMeTAD can be found in Figure S5. Devices fabricated with TTPA-DBQT were shown to perform superior to TTPA-DBST-based PSCs (Table 2). Efficiencies up to

Table 2. Device Performance of the New TTPA-DBQT and TTPA-DBST HTMs Compared with the Reference spiro-OMeTAD

HTM	scan direction	V_{oc} [V]	J_{sc} [mA cm ⁻²]	fill factor [%]	PCE [%]
TTPA-DBQT	forward	1.07	22.20	75.0	17.89
	reverse	1.09	22.23	74.4	18.08
TTPA-DBST	forward	1.03	19.51	66.7	13.37
	reverse	1.03	19.68	70.6	14.27
spiro-OMeTAD	forward	1.07	22.54	72.7	17.56
	reverse	1.08	22.60	73.1	17.96

18.08% (open circuit voltage (V_{oc}) = 1.09 V; short circuit current (J_{sc}) = 22.2 mA cm⁻²; fill factor (FF) = 74.4%) could be obtained using TTPA-DBQT, whereas for TTPA-DBST the champion device exhibited an efficiency of 14.27% (V_{oc} = 1.03 V; J_{sc} = 19.7 mA cm⁻²; FF = 70.6%) measuring in the reverse scan direction. Almost negligible hysteresis was observed for TTPA-DBQT with a performance difference between reverse and forward scan of only 1%, whereas for TTPA-DBST the difference in performance was around 6%. The performance for the solar cell based on spiro-OMeTAD was very close to that obtained for TTPA-DBQT with an efficiency of 17.96% (V_{oc} = 1.09 V; J_{sc} = 22.6 mA cm⁻²; FF = 73.1%). The lower performance of TTPA-DBST stemmed from its low solubility and therefore complicated processability. Tetrachloroethane was used as an alternative solvent which lead to the formation of a very thin HTM layer of only 20–50 nm as can be seen from the SEM image (Figure S7). Furthermore, the thin film turned out to be less uniform than for TTPA-DBQT looking at the finished devices displayed as an inset in Figure 3c. This indicates the formation of pinholes within the HTM layer, which would explain the reduced V_{oc} and J_{sc} of the TTPA-DBST devices due to direct contact of the gold layer with the perovskite material. The J_{sc} obtained from the *J*-*V* measurements and the integrated current densities from the external quantum efficiencies (EQEs) are in good agreement, within 5% (Figure S6).

Charge Transfer Properties and Conductivity. To have a better understanding of the charge extraction processes, steady-state photoluminescence (PL) was recorded. As shown in Figure S8, the pristine perovskite film exhibit a strong PL signal steaming from the radiative recombination of the photogenerated charge carriers. A significantly decreased PL signal is observed upon deposition of the HTMs on top of the

perovskite layer, provoked by an efficient quenching of the photogenerated charge carriers. This suggests a good hole extraction for both TTPA-DBST and TTPA-DBQT comparable to spiro-OMeTAD, which is in agreement with the well-aligned HOMO energy levels as discussed above. The more planar molecular structure predicted for TTPA-DBST (Figure S2) results in a more efficient hole extraction than for TTPA-DBQT, which may be attributed to better contact between the perovskite and the HTM. Intriguingly, the improved charge extraction capability of TTPA-DBST does not translate into a better photovoltaic performance than TTPA-DBQT. As mentioned before, the poor solubility of the former resulted in nonhomogeneous and poor film-forming ability, as observed in the cross-sectional image shown in Figure S7. The surface coverage of perovskite layer by TTPA-DBST is not uniformly distributed, leading to the formation of pinholes, which affects significantly not only the charge collection but also the device performance.

Further justification for the PSC efficiencies obtained with the different HTMs could be obtained by conductivity measurements (Figure 3d). The conductivity of the different molecules was measured on substrates having interdigitating gold electrodes with a channel length of 2.5 μm. The same concentration as for the device preparation was used by adding 6% of FK-209 as dopant. The highest conductivity was observed for TTPA-DBQT (4.25 × 10⁻⁴ S·cm⁻¹), slightly higher than that of spiro-OMeTAD (3.91 × 10⁻⁴ S·cm⁻¹). The conductivity of TTPA-DBST (6.25 × 10⁻⁵ S·cm⁻¹), on the other hand, was around 1 order of magnitude lower, which further corroborates its low J_{sc} , poor FF, and therefore lower PCEs compared with TTPA-DBQT.

CONCLUSIONS

In summary, we report the syntheses and study the properties of two new custom-made HTMs based on innovative two-dimensional heteroarenes as central scaffolds for highly efficient PSCs. These new derivatives comprise dibenzoquethiophene (DBQT) and dibenzosexithiophene (DBST), which are covalently linked to four *p*-methoxytriphenylamine units. A detailed characterization and comparison of the thermal and optoelectronic properties was conducted. Both HTMs are thermally stable with glass transition temperatures higher than 100 °C and exhibit very similar HOMO and LUMO energy levels, which ensure a good alignment with the valence band edge of the perovskite. Upon assessing both HTMs in mesoporous devices, remarkable light-to-energy conversion efficiencies of 18.1% and 14.27% are measured for TTPA-DBQT and TTPA-DBST, respectively, which are similar to the efficiency obtained for the widely used spiro-OMeTAD (17.96%). TTPA-DBQT shows not only the highest performance with no hysteresis but also better solubility (processability) and conductivity values, which are 1 order of magnitude higher than those measured for TTPA-DBST. The lower solubility of TTPA-DBST in chlorobenzene leads to poor coverage of the perovskite surface and to the formation of pinholes, which significantly affect the device performance. Good processability of the HTM from solution is a very important parameter for reaching high performing devices. Therefore, a compromise between the extended molecular structure and the solubility must be taken into account. Attaching longer alkyl chains can be envisioned as a complementary strategy to overcome this drawback, but it may affect other properties such as conductivity. Finally, promoting

446 the intermolecular assembly by π - π and S...S interactions
447 using fused oligothiophene-based π -conjugated systems as a
448 central core serves as an excellent approach for designing
449 highly efficient HTMs.

450 ■ ASSOCIATED CONTENT

451 ● Supporting Information

452 The Supporting Information is available free of charge on the
453 ACS Publications website at DOI: 10.1021/acs.chemmater.8b04003.
454

455 General materials and methods; synthetic procedures
456 and characterization, such as ^1H NMR, ^{13}C NMR, and
457 mass spectrometry (MALDI-TOF); computational details;
458 device fabrication and characterization, such as
459 hysteresis, EQE measurements, SEM, and steady-state
460 photoluminescence (PDF)

461 ■ AUTHOR INFORMATION

462 Corresponding Authors

463 *Homepage: <http://www.nazarionmartingroup.com/>. E-mail:
464 nazmar@ucm.es.

465 *E-mail: mdkhaja.nazeeruddin@epfl.ch.

466 *E-mail: enrique.orti@uv.es.

467 *E-mail: agustin.molina@imdea.org.

468 ORCID

469 Juan Aragón: 0000-0002-0415-9946

470 Enrique Ortí: 0000-0001-9544-8286

471 Nazario Martín: 0000-0002-5355-1477

472 Mohammad Khaja Nazeeruddin: 0000-0001-5955-4786

473 Author Contributions

474 [‡]J.U.-M. and I.W. contributed equally to this work.

475 Notes

476 The authors declare no competing financial interest.

477 ■ ACKNOWLEDGMENTS

478 We thank the Swiss National Funds for Scientific Research
479 contract number 200020L_172929/1, Project "Tailored
480 Design and in-depth understanding of perovskite solar
481 materials using in-house developed 3D/4D nanoscale ion-
482 beam analysis". Borun New Material Technology generously
483 supplied the high-quality spiro-OMeTAD. The authors also
484 thank the European Research Council (ERC-320441-Chir-
485 allcarbon), the Spanish Ministry of Economy and Compet-
486 itiveness MINECO (Project Nos. CTQ2014-52045-R,
487 CTQ2015-71154-P, CTQ2015-71936-REDT, and CTQ2016-
488 81911-REDT, Unidad de Excelencia Severo Ochoa SEV-2016-
489 0686, and Unidad de Excelencia María de Maeztu MDM-
490 2015-0538), the CAM (FOTOCARBON Project No. S2013/
491 MIT-2841), the Generalitat Valenciana (No. PROMETEO/
492 2016/135), and European Feder funds (No. CTQ2015-71154-
493 P). J.A. is grateful to MINECO for a "JdC-incorporación"
494 postdoctoral fellowship (No. IJCI-2015-26154).

495 ■ REFERENCES

496 (1) Kojima, A.; Teshima, K.; Shirai, Y.; Miyasaka, T. Organometal
497 Halide Perovskites as Visible-Light Sensitizers for Photovoltaic Cells.
498 *J. Am. Chem. Soc.* **2009**, *131*, 6050–6051.
499 (2) National Renewable Energy Laboratory. [http://www.nrel.gov/
500 ncpv/images/efficiency_chart.jpg](http://www.nrel.gov/ncpv/images/efficiency_chart.jpg) (accessed June 20, 2016).
501 (3) Ponceca, C. S.; Savenije, T. J.; Abdellah, M.; Zheng, K.; Yartsev,
502 A.; Pascher, T.; Harlang, T.; Chabera, P.; Pullerits, T.; Stepanov, A.;
503 Wolf, J.-P.; Sundström, V. Organometal Halide Perovskite Solar Cell

Materials Rationalized: Ultrafast Charge Generation, High and
504 Microsecond-Long Balanced Mobilities, and Slow Recombination. *J.*
505 *Am. Chem. Soc.* **2014**, *136*, 5189–5192.

(4) Savenije, T. J.; Ponceca, C. S.; Kunneman, L.; Abdellah, M.;
507 Zheng, K.; Tian, Y.; Zhu, Q.; Canton, S. E.; Scheblykin, I. G.;
508 Pullerits, T.; Yartsev, A.; Sundström, V. Thermally Activated Exciton
509 Dissociation and Recombination Control the Carrier Dynamics in
510 Organometal Halide Perovskite. *J. Phys. Chem. Lett.* **2014**, *5*, 2189–
511 2194.

(5) Oga, H.; Saeki, A.; Ogomi, Y.; Hayase, S.; Seki, S. Improved
513 Understanding of the Electronic and Energetic Landscapes of
514 Perovskite Solar Cells: High Local Charge Carrier Mobility, Reduced
515 Recombination, and Extremely Shallow Traps. *J. Am. Chem. Soc.* **2014**,
516 *136*, 13818–13825.

(6) Eperon, G. E.; Stranks, S. D.; Menelaou, C.; Johnston, M. B.;
518 Herz, L. M.; Snaith, H. J. Formamidinium lead trihalide: a broadly
519 tunable perovskite for efficient planar heterojunction solar cells.
520 *Energy Environ. Sci.* **2014**, *7*, 982–988.

(7) Stranks, S. D.; Eperon, G. E.; Grancini, G.; Menelaou, C.;
522 Alcocer, M. J. P.; Leijtens, T.; Herz, L. M.; Petrozza, A.; Snaith, H. J.
523 Electron-Hole Diffusion Lengths Exceeding 1 Micrometer in an
524 Organometal Trihalide Perovskite Absorber. *Science* **2013**, *342*, 341–
525 344.

(8) Dong, Q.; Fang, Y.; Shao, Y.; Mulligan, P.; Qiu, J.; Cao, L.;
527 Huang, J. Electron-hole diffusion lengths > 175 μm in solution-grown
528 $\text{CH}_3\text{NH}_3\text{PbI}_3$ single crystals. *Science* **2015**, *347*, 967.

(9) Xing, G.; Mathews, N.; Sun, S.; Lim, S. S.; Lam, Y. M.; Grätzel,
530 M.; Mhaisalkar, S.; Sum, T. C. Long-Range Balanced Electron- and
531 Hole-Transport Lengths in Organic-Inorganic $\text{CH}_3\text{NH}_3\text{PbI}_3$. *Science*
532 **2013**, *342*, 344–347.

(10) Kazim, S.; Nazeeruddin, M. K.; Grätzel, M.; Ahmad, S.
534 Perovskite as Light Harvester: A Game Changer in Photovoltaics.
535 *Angew. Chem., Int. Ed.* **2014**, *53*, 2812–2824.

(11) Saliba, M.; Matsui, T.; Seo, J.-Y.; Domanski, K.; Correa-Baena,
537 J.-P.; Nazeeruddin, M. K.; Zakeeruddin, S. M.; Tress, W.; Abate, A.;
538 Hagfeldt, A.; Grätzel, M. Cesium-containing triple cation perovskite
539 solar cells: improved stability, reproducibility and high efficiency.
540 *Energy Environ. Sci.* **2016**, *9*, 1989–1997.

(12) Bi, D.; Tress, W.; Dar, M. I.; Gao, P.; Luo, J.; Renevier, C.;
542 Schenk, K.; Abate, A.; Giordano, F.; Correa Baena, J.-P.; Decoppet, J.-
543 D.; Zakeeruddin, S. M.; Nazeeruddin, M. K.; Grätzel, M.; Hagfeldt, A.
544 Efficient luminescent solar cells based on tailored mixed-cation
545 perovskites. *Sci. Adv.* **2016**, *2*, No. e1501170.

(13) Zhang, J.; Hua, Y.; Xu, B.; Yang, L.; Liu, P.; Johansson, M. B.;
547 Vlachopoulos, N.; Kloo, L.; Boschloo, G.; Johansson, E. M. J.; Sun, L.;
548 Hagfeldt, A. The Role of 3D Molecular Structural Control in New
549 Hole Transport Materials Outperforming Spiro-OMeTAD in Perov-
550 skite Solar Cells. *Adv. Energy Mater.* **2016**, *6*, 1601062.

(14) Saliba, M.; Orlandi, S.; Matsui, T.; Aghazada, S.; Cavazzini, M.;
552 Correa-Baena, J.-P.; Gao, P.; Scopelliti, R.; Mosconi, E.; Dahmen, K.
553 H.; De Angelis, F.; Abate, A.; Hagfeldt, A.; Pozzi, G.; Grätzel, M.;
554 Nazeeruddin, M. K. A molecularly engineered hole-transporting
555 material for efficient perovskite solar cells. *Nat. Energy* **2016**, *1*, 15017.

(15) Bi, D.; Xu, B.; Gao, P.; Sun, L.; Grätzel, M.; Hagfeldt, A. Facile
557 synthesized organic hole transporting material for perovskite solar cell
558 with efficiency of 19.8%. *Nano Energy* **2016**, *23*, 138–144.

(16) Malinauskas, T.; Saliba, M.; Matsui, T.; Daskeviciene, M.;
560 Urnikaitė, S.; Grätzel, M.; Send, R.; Wonneberger, H.; Bruder, I.;
561 Grätzel, M.; Getautis, V.; Nazeeruddin, M. K. Branched methox-
562 ydiphenylamine-substituted fluorene derivatives as hole transporting
563 materials for high-performance perovskite solar cells. *Energy Environ.*
564 *Sci.* **2016**, *9*, 1681–1686.

(17) Cabau, L.; Garcia-Benito, I.; Molina-Ontoria, A.; Montcada, N.
566 F.; Martin, N.; Vidal-Ferran, A.; Palomares, E. Diarylamino-
567 substituted tetraarylethene (TAE) as an efficient and robust hole
568 transport material for 11% methyl ammonium lead iodide perovskite
569 solar cells. *Chem. Commun.* **2015**, *51*, 13980–13982.

(18) Cho, I.; Jeon, N. J.; Kwon, O. K.; Kim, D. W.; Jung, E. H.; Noh,
571 J. H.; Seo, J.; Seok, S. I.; Park, S. Y. Indolo[3,2-b]indole-based

- 573 crystalline hole-transporting material for highly efficient perovskite
574 solar cells. *Chem. Sci.* **2017**, *8*, 734–741.
- 575 (19) Chen, C.; Cheng, M.; Liu, P.; Gao, J.; Kloo, L.; Sun, L.
576 Application of benzodithiophene based A–D–A structured materials
577 in efficient perovskite solar cells and organic solar cells. *Nano Energy*
578 **2016**, *23*, 40–49.
- 579 (20) Bi, D.; Mishra, A.; Gao, P.; Franckevičius, M.; Steck, C.;
580 Zakeeruddin, S. M.; Nazeeruddin, M. K.; Bäuerle, P.; Grätzel, M.;
581 Hagfeldt, A. High-Efficiency Perovskite Solar Cells Employing a S,N-
582 Heteropentacene-based D–A Hole-Transport Material. *ChemSusChem*
583 **2016**, *9*, 433–438.
- 584 (21) Wang, C.; Dong, H.; Hu, W.; Liu, Y.; Zhu, D. Semiconducting
585 π -Conjugated Systems in Field-Effect Transistors: A Material Odyssey
586 of Organic Electronics. *Chem. Rev.* **2012**, *112*, 2208–2267.
- 587 (22) Dang, D.; Fan, J.; Wang, X.; Xiao, M.; Shi, J.; Zhou, P.; Duan,
588 X.; Lei, G.; Liu, Y.; Zhu, W. Influence of the fused hetero-aromatic
589 centers on molecular conformation and photovoltaic performance of
590 solution-processed organic solar cells. *New J. Chem.* **2015**, *39*, 2224–
591 2232.
- 592 (23) Dang, D.; Xiao, M.; Zhou, P.; Zhong, J.; Fan, J.; Su, N.; Xiong,
593 W.; Yang, C.; Wang, Q.; Wang, Y.; Pei, Y.; Yang, R.; Zhu, W. Tuning
594 the Isomeric Fused Heteroaromatic Core of Small Donor–Acceptor
595 Molecules to Alter Their Crystalline Nature and Enhance Photo-
596 voltaic Performance. *Eur. J. Org. Chem.* **2015**, *2015*, 820–827.
- 597 (24) Dang, D.; Zhou, P.; Zhong, J.; Fan, J.; Wang, Z.; Wang, Y.; Pei,
598 Y.; Bao, X.; Yang, R.; Hu, W.; Zhu, W. Novel wide band-gap polymer
599 utilizing fused hetero-aromatic unit for efficient polymer solar cells
600 and field-effect transistors. *Polymer* **2014**, *55*, 6708–6716.
- 601 (25) Garcia-Benito, I.; Zimmermann, I.; Urieta-Mora, J.; Arago, J.;
602 Molina-Ontoria, A.; Orti, E.; Martín, N.; Nazeeruddin, M. K.
603 Isomerism effect on the photovoltaic properties of benzotrithio-
604 phene-based hole-transporting materials. *J. Mater. Chem. A* **2017**, *5*,
605 8317–8324.
- 606 (26) Molina-Ontoria, A.; Zimmermann, I.; Garcia-Benito, I.; Gratia,
607 P.; Roldán-Carmona, C.; Aghazada, S.; Graetzel, M.; Nazeeruddin, M.
608 K.; Martín, N. Benzotrithiophene-Based Hole-Transporting Materials
609 for 18.2% Perovskite Solar Cells. *Angew. Chem., Int. Ed.* **2016**, *55*,
610 6270–6274.
- 611 (27) García-Benito, I.; Zimmermann, I.; Urieta-Mora, J.; Aragón, J.;
612 Calbo, J.; Perles, J.; Serrano, A.; Molina-Ontoria, A.; Ortí, E.; Martín,
613 N.; Nazeeruddin, M. K. Heteroatom Effect on Star-Shaped Hole-
614 Transporting Materials for Perovskite Solar Cells. *Adv. Funct. Mater.*
615 **2018**, *28*, 1801734.
- 616 (28) Zimmermann, I.; Urieta-Mora, J.; Gratia, P.; Aragón, J.;
617 Grancini, G.; Molina-Ontoria, A.; Ortí, E.; Martín, N.; Nazeeruddin,
618 M. K. High-Efficiency Perovskite Solar Cells Using Molecularly
619 Engineered, Thiophene-Rich, Hole-Transporting Materials: Influence
620 of Alkyl Chain Length on Power Conversion Efficiency. *Adv. Energy*
621 *Mater.* **2017**, *7*, 1601674.
- 622 (29) Aragón, J.; Ponce Ortiz, R.; Nieto-Ortega, B.; Hernández, V.;
623 Casado, J.; Facchetti, A.; Marks, T. J.; Viruela, P. M.; Ortí, E.; López
624 Navarrete, J. T. Carbonyl-Functionalized Quaterthiophenes: A Study
625 of the Vibrational Raman and Electronic Absorption/Emission
626 Properties Guided by Theoretical Calculations. *ChemPhysChem*
627 **2012**, *13*, 168–176.
- 628 (30) Aragón, J.; Viruela, P. M.; Gierschner, J.; Orti, E.; Milian-
629 Medina, B. Oligothienoacenes versus oligothiophenes: impact of ring
630 fusion on the optical properties. *Phys. Chem. Chem. Phys.* **2011**, *13*,
631 1457–1465.
- 632 (31) Aragón, J.; Viruela, P. M.; Ortí, E.; Malavé Osuna, R.; Vercelli,
633 B.; Zotti, G.; Hernández, V.; López Navarrete, J. T.; Henssler, J. T.;
634 Matzger, A. J.; Suzuki, Y.; Yamaguchi, S. Neutral and Oxidized
635 Triisopropylsilyl End-Capped Oligothienoacenes: A Combined
636 Electrochemical, Spectroscopic, and Theoretical Study. *Chem. - Eur.*
637 *J.* **2010**, *16*, 5481–5491.
- 638 (32) Malavé Osuna, R.; Hernández, V.; López Navarrete, J. T.;
639 Aragón, J.; Viruela, P. M.; Ortí, E.; Suzuki, Y.; Yamaguchi, S.; Henssler,
640 J. T.; Matzger, A. J. FT Raman and DFT Study on a Series of All-anti
Oligothienoacenes End-Capped with Triisopropylsilyl Groups. *ChemPhysChem* **2009**, *10*, 3069–3076.
- (33) Sokolov, A. N.; Atahan-Evrenk, S.; Mondal, R.; Akkerman, H.
B.; Sánchez-Carrera, R. S.; Granados-Focil, S.; Schrier, J.; Mannsfeld,
S. C. B.; Zoombelt, A. P.; Bao, Z.; Aspuru-Guzik, A. From
computational discovery to experimental characterization of a high
hole mobility organic crystal. *Nat. Commun.* **2011**, *2*, 437.
- (34) Yao, Y.; Dong, H.; Hu, W. Charge Transport in Organic and
Polymeric Semiconductors for Flexible and Stretchable Devices. *Adv.*
Mater. **2016**, *28*, 4513–4523.
- (35) Kim, Y. C.; Jeon, N. J.; Noh, J. H.; Yang, W. S.; Seo, J.; Yun, J.
S.; Ho-Baillie, A.; Huang, S.; Green, M. A.; Seidel, J.; Ahn, T. K.;
Seok, S. I. Beneficial Effects of PbI₂ Incorporated in Organo-Lead
Halide Perovskite Solar Cells. *Adv. Energy Mater.* **2016**, *6*, 1502104.
- (36) Jeon, N. J.; Noh, J. H.; Yang, W. S.; Kim, Y. C.; Ryu, S.; Seo, J.;
Seok, S. I. Compositional engineering of perovskite materials for high-
performance solar cells. *Nature* **2015**, *517*, 476–80.